TECHNICAL DATA DATA SHEET 747, REV. -

# HERMETIC POWER MOSFET N-CHANNEL

### **FEATURES:**

- 600 Volt, 0.60 Ohm, 11A MOSFET
- Isolated Hermetic Metal Package
- Fast Switching
- Low R<sub>DS (on)</sub>
- Electrically Equivalent to IRFPC50

## **MAXIMUM RATINGS**

ALL RATINGS ARE AT  $T_c = 25^{\circ}$ C UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
GATE TO SOURCE VOLTAGE	$V_{GS}$	-		±20	Volts
ON-STATE DRAIN CURRENT	I <sub>D</sub>	-	-	11	Amps
PULSED DRAIN CURRENT @ $T_C = 25^{\circ}C$	I <sub>DM</sub>	ı	ı	44	Amps
OPERATING AND STORAGE TEMPERATURE	T <sub>J</sub> /T <sub>STG</sub>	-55	ı	+150	°C
TOTAL DEVICE DISSIPATION @ $T_C = 25^{\circ}C$	$P_{D}$	-		430	Watts
THERMAL RESISTANCE, JUNCTION TO CASE	$R_{\theta JC}$	-	-	0.29	°C/W

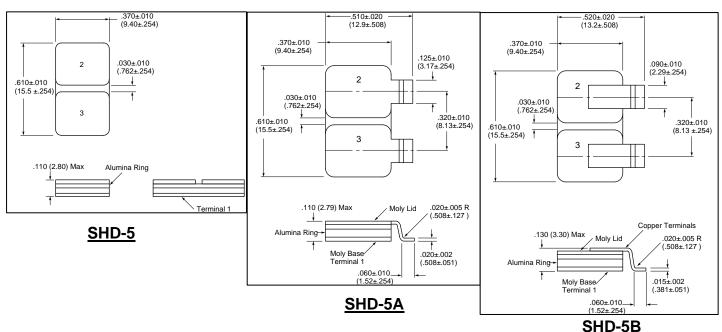
## **ELECTRICAL CHARACTERISTICS**

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DRAIN TO SOURCE BREAKDOWN VOLTAGE	$BV_{DSS}$	600	-	-	Volts
$V_{GS} = 0V, I_{D} = 1.0 \text{ mA}$					
STATIC DRAIN TO SOURCE ON STATE RESISTANCE					
$V_{GS} = 10V, I_{D} = 6.0A$	R <sub>DS(ON)</sub>	-	-	0.60	Ω
GATE THRESHOLD VOLTAGE $V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	$V_{GS(th)}$	2.0	-	4.0	Volts
FORWARD TRANSCONDUCTANCE					S(1/Ω)
$V_{DS} = 100V$ ,	$g_{fs}$	5.7	-	-	, ,
$I_{DS} = 6.0A$					
ZERO GATE VOLTAGE DRAIN CURRENT					
$V_{DS} = Max. rating, V_{GS} = 0V$	$I_{DSS}$	-	-	100	μΑ
$T_J = 25^{\circ}C$					·
ZERO GATE VOLTAGE DRAIN CURRENT					
$V_{DS} = 0.8 \text{ x Max. rating}, V_{GS} = 0V$	$I_{DSS}$	-	-	500	μΑ
T <sub>J</sub> = 125°C					
GATE TO SOURCE LEAKAGE FORWARD V <sub>GS</sub> = 20V	I <sub>GSS</sub>	-	-	100	nA
GATE TO SOURCE LEAKAGE REVERSE V <sub>GS</sub> = -20V				-100	
TURN ON DELAY TIME $V_{DD} = 300V$ ,	$t_{d(ON)}$	-	18	-	
RISE TIME $I_D = 11A$ ,	t <sub>r</sub>		37		nsec
TURN OFF DELAY TIME $R_G = 6.2\Omega$	$t_{d(OFF)}$		88		
FALL TIME	t <sub>f</sub>		36		
DIODE FORWARD VOLTAGE $T_C = 25^{\circ}C$ , $I_S = 11A$ ,	V <sub>SD</sub>	-	-	1.4	Volts
$V_{GS} = 0V$					
REVERSE RECOVERY TIME $T_J = 25^{\circ}C$ ,	t <sub>rr</sub>	-	550	830	
$I_F = 11A$					nsec
di/dt = 100A/μsec					
INPUT CAPACITANCE $V_{GS} = 0 \text{ V}$	C <sub>iss</sub>	-	2700	-	
OUTPUT CAPACITANCE V <sub>DS</sub> = 25 V	$C_{oss}$		300		pF
REVERSE TRANSFER CAPACITANCE f = 1.0MHz	$C_{rss}$		61		•

#### **SENSITRON**

DATA SHEET 747, REVISION -

#### **MECHANICAL DIMENSIONS: in Inches / mm**



## **PINOUT TABLE**

DEVICE TYPE	PIN 1	PIN 2	PIN 3
MOSFET, SURFACE MOUNT SHD-5, 5A, 5B PACKAGE	DRAIN	SOURCE	GATE

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